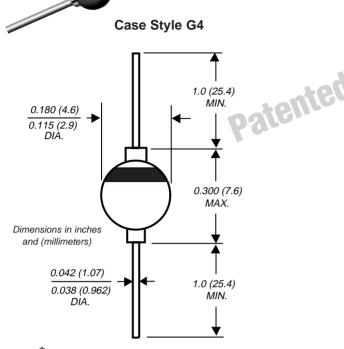
# G4A thru G4J

#### Vishay Semiconductors formerly General Semiconductor

**Glass Passivated Junction Rectifiers** 



\*Brazed-lead assembly is covered by Patent No. 3,930,306

### **Features**

Reverse Voltage 50 to 600V Forward Current 3.0A

- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Hermetically sealed package
- 3.0 ampere operation at TA=75°C with no thermal runaway
- Typical IR less than 0.1μA
- Capable of meeting environmental standards of MIL-S-19500
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### **Mechanical Data**

Case: Solid glass body

**Terminals:** Solder plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

#### Mounting Position: Any

Weight: 0.037 oz., 1.04 g

#### Packaging Codes – Options:

- 1-3K per Bulk box, 18k/ carton
- 4 2K per 13" reel (52.4mm Tape), 8K/carton

### Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	G4A	G4B	G4D	G4G	G4J	Unit
Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	V
Maximum RMS voltage	VRMS	35	70	140	280	420	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA = 70°C	IF(AV)	3.0				A	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	100				A	
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length at TA = 70°C	I <sub>R(AV)</sub>			200			μA
Typical thermal resistance <sup>(1)</sup>	R <sub>θJA</sub> R <sub>θJL</sub>	22 12				°C/W	
Operating junction and storage temperature range	TJ, TSTG	-65 to +175				°C	

## Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Maximum instantaneous forward voltage at 3.0	A VF	1.1	V
	25°C 100°C IR	1.0 100	μA
Typical reverse recovery time at $I_F = 0.5A$ , $I_R = 1.0A$ , $I_{rr} = 0.25A$	trr	5.0	μs
Typical junction capacitance at 4.0V, 1MHz	CJ	40	pF

Note: (1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, with both leads mounted between heatsinks

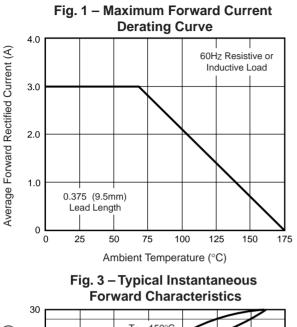
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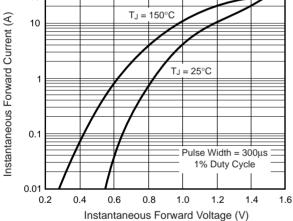
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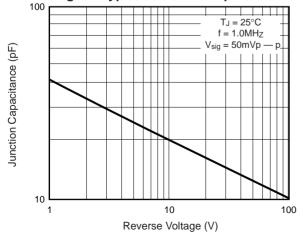
#### Ratings and

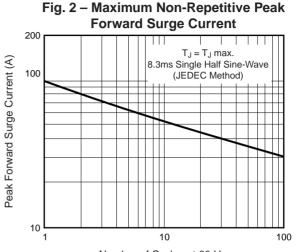
Characteristic Curves (TA = 25°C unless otherwise noted)











Number of Cycles at 60 Hz



